



MMBTA05 / MMBTA06

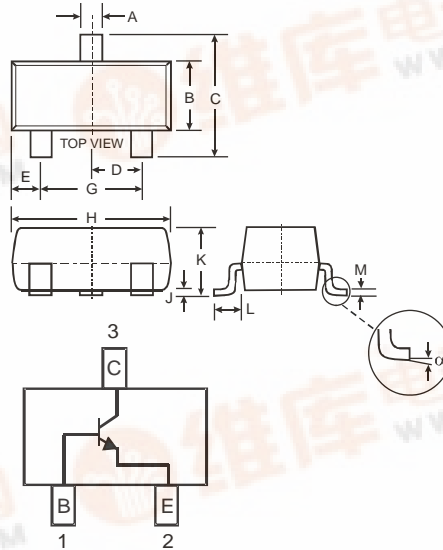
NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (MMBTA55 / MMBTA56)
- Ideal for Low Power Amplification and Switching
- **Lead Free/RoHS Compliant (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

- Case: SOT-23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- MMBTA05 Marking (See Page 3): K1G, K1H
- MMBTA06 Marking (See Page 3): K1G
- Ordering & Date Code Information: See Page 3
- Weight: 0.008 grams (approximate)



SOT-23		
Dim	Min	Max
A	0.37	0.51
B	1.20	1.40
C	2.30	2.50
D	0.89	1.03
E	0.45	0.60
G	1.78	2.05
H	2.80	3.00
J	0.013	0.10
K	0.903	1.10
L	0.45	0.61
M	0.085	0.180
α	0°	8°
All Dimensions in mm		

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	MMBTA05	MMBTA06	Unit
Collector-Base Voltage	V _{CBO}	60	80	V
Collector-Emitter Voltage	V _{CEO}	60	80	V
Emitter-Base Voltage	V _{EBO}	4.0		V
Collector Current - Continuous (Note 1)	I _C	500		mA
Power Dissipation (Note 1)	P _d	300		mW
Thermal Resistance, Junction to Ambient (Note 1)	R _{θJA}	417		°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150		°C

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 2)					
Collector-Base Breakdown Voltage	V _{(BR)CBO}	60	—	V	I _C = 100μA, I _E = 0
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	60	—	V	I _C = 1.0mA, I _B = 0
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	4.0	—	V	I _E = 100μA, I _C = 0
Collector Cutoff Current	I _{CBO}	—	100	nA	V _{CB} = 60V, I _E = 0 V _{CB} = 80V, I _E = 0
Collector Cutoff Current	I _{CES}	—	100	nA	V _{CE} = 60V, I _{BO} = 0V V _{CE} = 80V, I _{BO} = 0V
ON CHARACTERISTICS (Note 2)					
DC Current Gain	h _{FE}	100	—	—	I _C = 10mA, V _{CE} = 1.0V I _C = 100mA, V _{CE} = 1.0V
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	—	0.25	V	I _C = 100mA, I _B = 10mA
Base-Emitter Saturation Voltage	V _{BE(SAT)}	—	1.2	V	I _C = 100mA, V _{CE} = 1.0V
SMALL SIGNAL CHARACTERISTICS					
Current Gain-Bandwidth Product	f _T	100	—	MHz	V _{CE} = 2.0V, I _C = 10mA, f = 100MHz

Note: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
2. Short duration pulse test used to minimize self-heating effect.
3. No purposefully added lead.



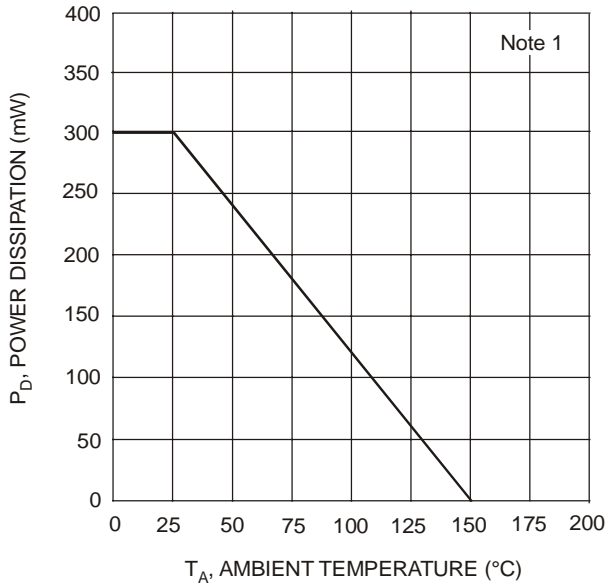


Fig. 1, Max Power Dissipation vs Ambient Temperature

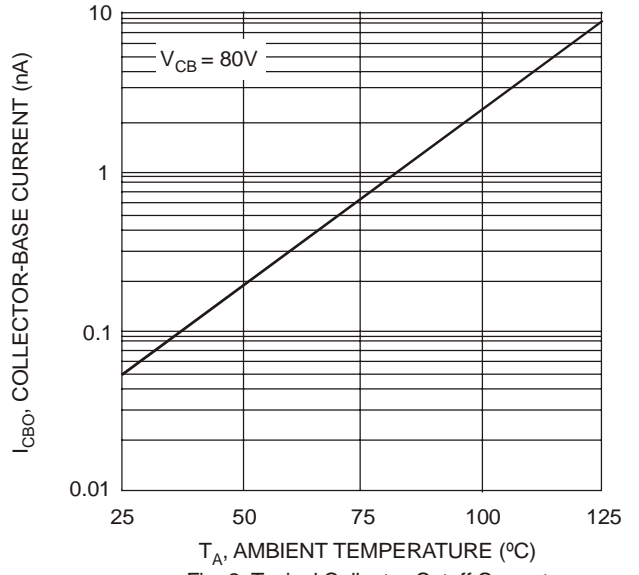


Fig. 2, Typical Collector-Cutoff Current vs. Ambient Temperature

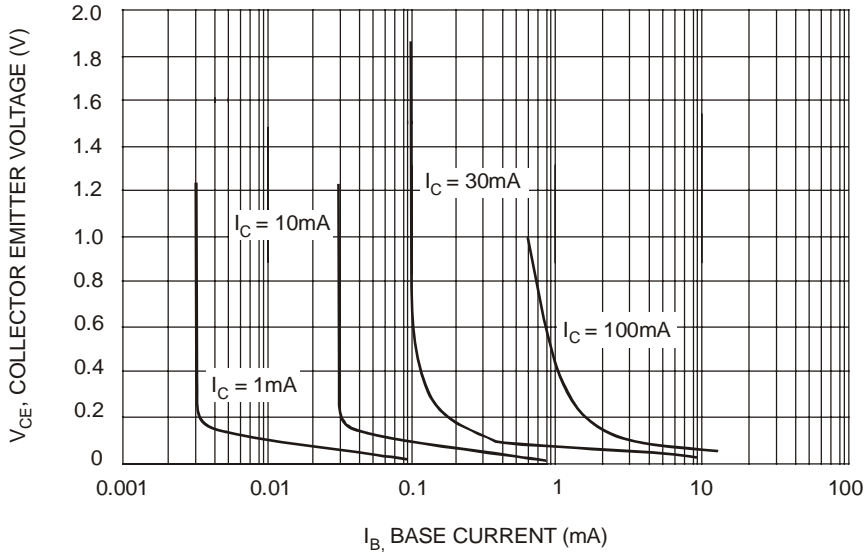


Fig. 3, Typical Collector Saturation Region

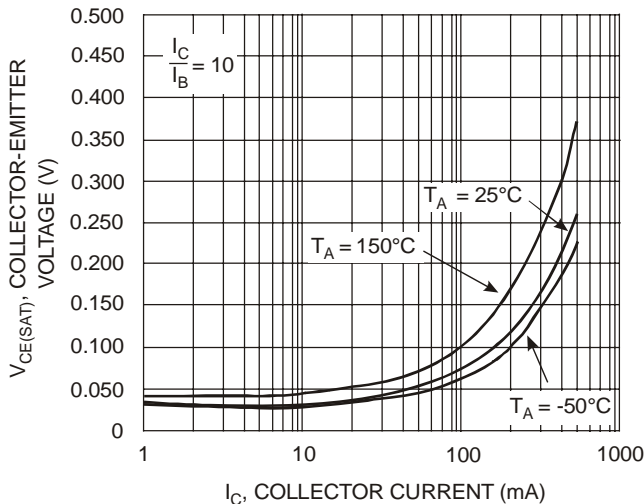


Fig. 4, Collector Emitter Saturation Voltage vs. Collector Current

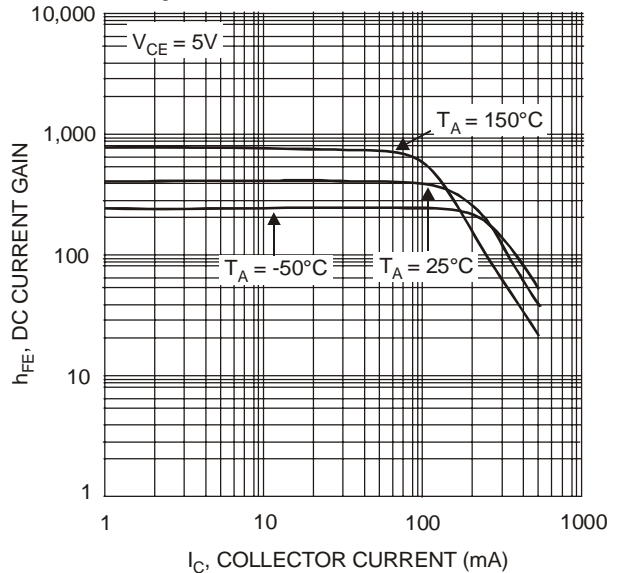


Fig. 5, DC Current Gain vs Collector Current

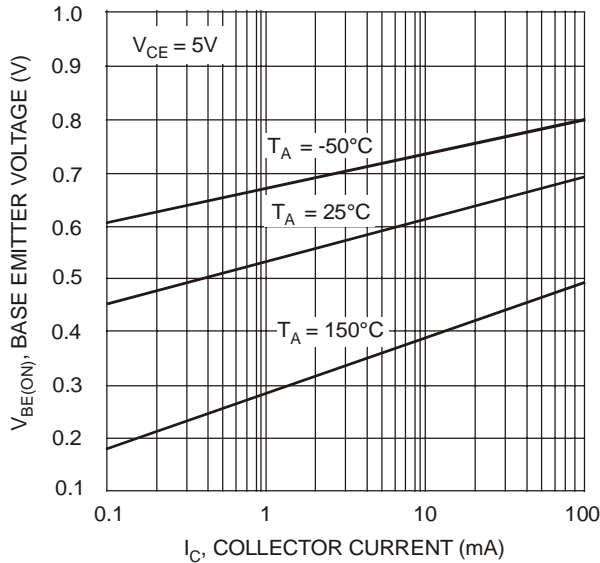


Fig. 6, Base Emitter Voltage vs Collector Current

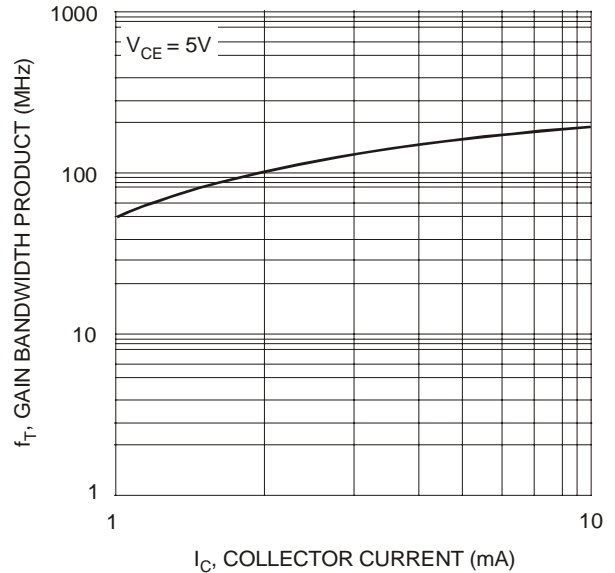


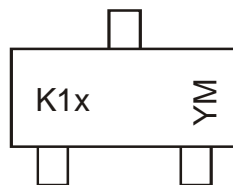
Fig. 7, Gain Bandwidth Product vs Collector Current

Ordering Information (Note 4)

Device	Packaging	Shipping
MMBTA05-7-F	SOT-23	3000/Tape & Reel
MMBTA06-7-F	SOT-23	3000/Tape & Reel

Notes: 4. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



K1x = Product Type Marking Code, e.g. K1G
 YM = Date Code Marking
 Y = Year ex: N = 2002
 M = Month ex: 9 = September

Date Code Key

Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	J	K	L	M	N	P	R	S	T	U	V	W	X	Y	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.